

#### 40V MATCHED PAIR NPN SMALL SIGNAL TRANSISTOR IN SOT363

#### **Features**

- BV<sub>CEO</sub> > 40V
- I<sub>C</sub> = 200mA High Collector Current
- Pair of NPN Transistors that are Intrinsically Matched (Note 1)
- 2% Matching on Current Gain (hFE)
- 2mV Matching on Base-Emitter Voltage (VBE)
- Fully Internally Isolated in a Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 2 & 3)
- Halogen and Antimony Free. "Green" Device (Note 4)
- An Automotive-Compliant Part is Available Under Separate Datasheet DIODES™ (DMMT3904WQ)

#### **Mechanical Data**

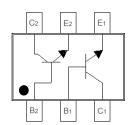
- Package: SOT363
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 <a>®3</a>
- Weight: 0.006 grams (Approximate)

## **Applications**

- Current mirrors
- Differential and instrumentation amplifiers
- Comparators



Top View



Device Schematic and Pin-Out Top View

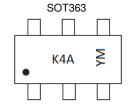
### Ordering Information (Note 5)

Part Number	Paokago	Marking Reel Size (inches) Tape Width (mm)		Pac	king	
Fait Number	Package	Iviai Kii ig	neer Size (inches)	rape width (illin)	Qty.	Carrier
DMMT3904W-7-F	SOT363	K4A	7	8	3,000	Reel

Notes:

- 1. Intrinsically matched pair as this is built with adjacent die from the same wafer.
- 2. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 3. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 4. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



K4A = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: J = 2022) M = Month (ex: 6 = June)

Date Code Key

Date Odde Ney												
Year	2002		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0		J	K	Ш	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{\sf CEO}$	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current	Ic	200	mA

# Thermal Characteristics – Total Device (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) Total Device	P <sub>D</sub>	200	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

# ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

## Thermal Characteristics - Total Device

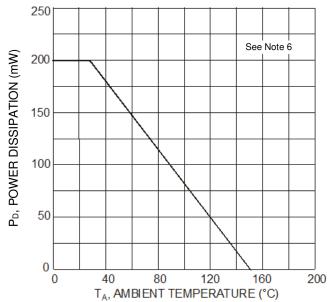


Figure 1. Power Derating Curve (Total Device)

<sup>6.</sup> For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR-4 PCB; the device is measured under still air conditions whilst operating in a steady-state.

<sup>7.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS			71-			
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60	_	_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	40	_	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6.0	_	_	V	$I_E = 100 \mu A, I_C = 0$
Collector Cutoff Current	I <sub>CEX</sub>	_	_	50	nA	V <sub>CE</sub> = 30V, V <sub>EB(OFF)</sub> = 3.0V
Base Cutoff Current	I <sub>BL</sub>	_	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 8)	<u>'</u>		l.	l .		. ,
DC Current Gain	h <sub>FE</sub>	40 70 100 60 30	_	300 — —	_	$\begin{split} &I_{C} = 100 \mu A, \ V_{CE} = 1.0 V \\ &I_{C} = 1.0 m A, \ V_{CE} = 1.0 V \\ &I_{C} = 10 m A, \ V_{CE} = 1.0 V \\ &I_{C} = 50 m A, \ V_{CE} = 1.0 V \\ &I_{C} = 100 m A, \ V_{CE} = 1.0 V \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_	_	200 300	mV	$I_C = 10mA$ , $I_B = 1.0mA$ $I_C = 50mA$ , $I_B = 5.0mA$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	650 —	_	850 950	mV	$I_C = 10mA$ , $I_B = 1.0mA$ $I_C = 50mA$ , $I_B = 5.0mA$
MATCHING CHARACTERISTICS						
DC Current Gain Matching (Note 9)	h <sub>FE1</sub> / h <sub>FE2</sub>	_	1	2	%	$I_C = 2mA$ , $V_{CE} = 5V$
Base-Emitter Voltage Matching (Note 10)	V <sub>BE1</sub> - V <sub>BE2</sub>	_	1	2	mV	$I_C = 2mA$ , $V_{CE} = 5V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)1</sub> / V <sub>CE(sat)2</sub>	_	1	2	%	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)1</sub> / V <sub>BE(sat)2</sub>	_	1	2	%	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA
SMALL SIGNAL CHARACTERISTICS						•
Output Capacitance	C <sub>obo</sub>	_	_	4.0	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	C <sub>ibo</sub>	_	_	8.0	pF	$V_{EB} = 0.5V$ , $f = 1.0MHz$ , $I_{C} = 0$
Input Impedance	h <sub>ie</sub>	1.0	_	10	kΩ	
Voltage Feedback Ratio	h <sub>re</sub>	0.5	_	8	x 10 <sup>-4</sup>	$V_{CE} = 10V, I_{C} = 1.0mA,$
Small Signal Current Gain	h <sub>fe</sub>	100	_	400	_	f = 1.0kHz
Output Admittance	h <sub>oe</sub>	1.0	_	40	μS	
Current Gain-Bandwidth Product	f <sub>T</sub>	300	_	_	MHz	$V_{CE} = 20V, I_{C} = 10mA,$ f = 100MHz
Noise Figure	NF	_	_	5.0	dB	$V_{CE} = 5.0V$ , $I_{C} = 100\mu A$ , $R_{S} = 1.0k\Omega$ , $f = 1.0kHz$
SWITCHING CHARACTERISTICS						
Delay Time	t <sub>d</sub>	_		35	ns	$V_{CC} = 3.0V, I_{C} = 10mA,$
Rise Time	t <sub>r</sub>		_	35	ns	$V_{BE(on)} = -0.5V, I_{B1} = 1.0mA$
Storage Time	ts		_	200	ns	$V_{CC} = 3.0V, I_{C} = 10mA,$
Fall Time	t <sub>f</sub>			50	ns	$I_{B1} = -I_{B2} = 1.0 \text{mA}$

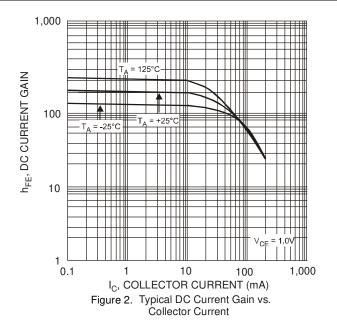
Notes:

<sup>8.</sup> Measured under pulsed conditions. Pulse width  $\leqslant$  300µs. Duty cycle  $\leqslant$  2%. 9. Is the ratio of one transistor compared to the other transistor.

<sup>10.</sup>  $V_{\text{BE1}}$  -  $V_{\text{BE2}}$  is the absolute difference of one transistor compared to the other transistor.



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



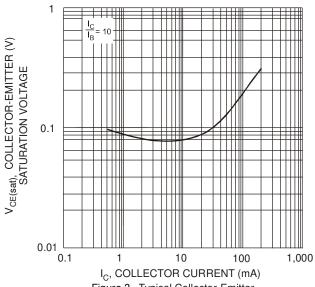
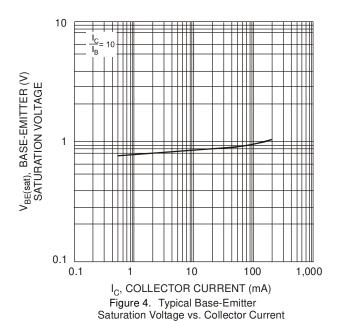


Figure 3. Typical Collector-Emitter Saturation Voltage vs. Collector Current



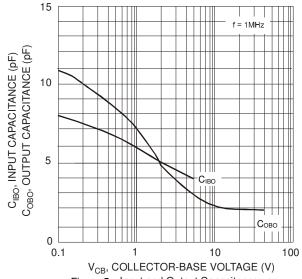


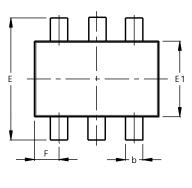
Figure 5. Input and Output Capacitance vs. Collector-Base Voltage

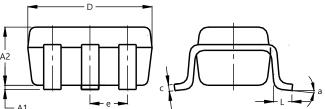


# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT363



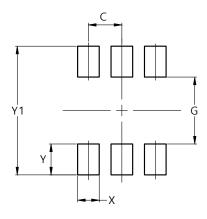


SOT363							
Dim	Min	Max	Тур				
<b>A</b> 1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.10	0.30	0.25				
C	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	0	.650 B	SC				
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	Dimen	sions	in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT363**



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
Y1	2.500



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